

Serial No. 09/928,474



Docket No.: 006301 USA/Consilium/Consilium

PATENT/OFFICIAL

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of :  
Badri N. KRISHNAMURTHY et al. :  
Serial No. 09/928,474 : Group Art Unit: 2812  
Filed: August 14, 2001 : Examiner: Andre' C. Stevenson  
For: EXPERIMENT MANAGEMENT SYSTEM, METHOD AND MEDIUM

**SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT**

Honorable Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This submission does not constitute a representation that a search has been made or that no better art exists and does not constitute an admission or representation that any of the listed documents is material or constitutes prior art. If it should be determined that any of the listed documents does not constitute prior art under the United States law, Applicants reserve the right to present to the Office the relevant facts and law regarding the appropriate status of such

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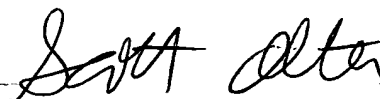
The references listed on Sheet 1 of the attached PTO-1449 Forms were cited in a patentability investigation and/or a corresponding foreign or PCT application relating to the above-referenced application. The remaining references are from potentially related patent applications, and possibly other sources.

The referenced patent application was finally rejected on June 3, 2004. Applicants petition for consideration of the enclosed documents by the Examiner. The petition fee of \$180.00 pursuant to 37 CFR § 1.17(p) is attached. The Commissioner is authorized to charge any deficiency in any fees pursuant to 37 CFR § 1.17 associated with this communication and to credit any excess payment to Deposit Account No. 08-0219.

Respectfully submitted,

Wilmer Cutler Pickering Hale and Dorr LLP

The PTO did not receive the following  
listed item(s) Fee \$180.00



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3



<b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)</b>				ATTY. DOCKET NO. 006301 USA/ Consilium/Consilium		SERIAL NO. 09/928,474	
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<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE	
	4,957,605	09/18/90	Hurwitt et al.			04/17/89	
	5,240,552	08/31/93	Yu et al.			12/11/91	
	5,369,544	11/29/94	Mastrangelo			04/05/93	
	5,444,837	08/22/95	Bomans et al.			12/29/93	
	5,665,214	09/09/97	Iturralde			05/03/95	
	5,695,810	12/09/97	Dubin et al.			11/20/96	
	5,824,599	10/20/98	Schacham-Diamand et al.			01/16/96	
	5,825,356	10/20/98	Habib et al.			03/18/96	
	5,831,851	11/03/98	Eastburn et al.			03/21/95	
	5,838,951	11/17/98	Song			08/28/96	
	5,859,777	01/12/99	Yokoyama et al.			05/13/97	
	5,871,805	02/16/99	Lemelson			04/08/96	
	5,943,550	08/24/99	Fulford, Jr. et al.			03/29/96	
	5,975,994	11/02/99	Sandhu et al.			06/11/97	
	6,012,048	01/04/00	Gustin et al.			05/30/97	
	6,037,664	03/14/00	Zhao et al.			03/31/98	
	6,059,636	05/09/00	Inaba et al.			07/09/98	
	6,096,649	08/01/00	Jang			10/25/99	
	6,100,195	08/08/00	Chan et al.			12/28/98	
	6,113,462	09/05/00	Yang			12/18/97	
	6,114,238	09/05/00	Liao			05/20/98	
	6,150,270	11/21/00	Matsuda et al.			01/07/99	
	6,157,864	12/05/00	Schwenke et al.			05/08/98	
	6,181,013 B1	01/30/01	Liu et al.			03/13/00	
	6,212,961 B1	04/10/01	Dvir			02/11/99	
	6,226,563 B1	05/01/01	Lim			09/04/98	
	6,228,280 B1	05/08/01	Li et al.			05/06/98	
	6,230,069 B1	05/08/01	Campbell et al.			06/26/98	
	6,237,050 B1	05/22/01	Kim et al.			09/04/98	
EXAMINER				DATE CONSIDERED			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.



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**U.S. PATENT DOCUMENTS**

EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
	2001/0006873 A1	07/05/01	Moore			02/13/01
	6,259,160 B1	07/10/01	Lopatin et al.			04/21/99
	6,268,270 B1	07/31/01	Scheid et al.			10/29/99
	6,277,014 B1	08/21/01	Chen et al.			10/09/98
	6,281,127 B1	08/28/01	Shue			04/15/99
	6,291,367 B1	09/18/01	Kelkar			06/01/00
	6,317,643 B1	11/13/01	Dmochowski			03/31/99
	6,339,727 B1	01/15/02	Ladd			12/21/98
	6,355,559 B1	03/12/02	Havemann et al.			11/03/00
	6,381,564	04/30/02	Davis et al.			05/03/99
	6,391,780 B1	05/21/02	Shih et al.			08/23/99
	6,417,014 B1	07/09/02	Lam et al.			10/19/99
	6,427,093 B1	07/30/02	Toprac			10/07/99
	6,432,728 B1	08/13/02	Tai et al.			10/16/00
	6,449,524 B1	09/10/02	Miller et al.			01/04/00
	6,455,415 B1	09/24/02	Lopatin et al.			04/16/01
	6,465,263 B1	10/15/02	Coss, Jr. et al.			01/04/00
	2002/0165636 A1	11/07/02	Hasan			04/24/02
	6,484,064 B1	11/19/02	Campbell			10/05/99
	2002/0183986 A1	12/05/02	Stewart et al.			05/30/01
	6,495,452 B1	12/17/02	Shih			08/18/99
	2002/0193899 A1	12/19/02	Shanmugasundram et al.			05/01/02
	2003/0017256 A1	01/23/03	Shimane			06/12/02
	6,515,368 B1	02/04/03	Lopatin et al.			12/07/01
	6,517,414 B1	02/11/03	Tobin et al.			03/10/00
	6,528,409 B1	03/04/03	Lopatin et al.			04/29/02
	6,529,789	03/04/03	Campbell et al.			03/14/02
	6,532,555 B1	03/11/03	Miller et al.			10/29/99
	6,535,783 B1	03/18/03	Miller et al.			03/05/01

<b>EXAMINER</b>	<b>DATE CONSIDERED</b>
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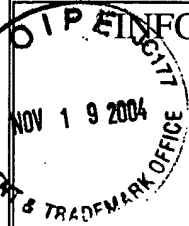
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	6,537,912 B1	03/25/03	Agarwal			08/25/00	
	6,541,401 B1	04/01/03	Herner et al.			07/31/00	
	6,546,508 B1	04/08/03	Sonderman et al.			10/29/99	
	6,556,881 B1	04/29/03	Miller			09/09/99	
	6,580,958 B1	06/17/03	Takano			11/22/99	
	6,605,549 B2	08/12/03	Leu et al.			09/29/01	
	2003/0154062	08/14/03	Daft et al.			10/15/01	
	6,607,976 B2	08/19/03	Chen et al.			09/25/01	
	6,609,946 B1	08/26/03	Tran			07/14/00	
	6,616,513 B1	09/09/03	Osterheld			04/05/01	
	6,624,075 B1	09/23/03	Lopatin et al.			11/05/02	
	6,630,741 B1	10/07/03	Lopatin et al.			12/07/01	
	6,652,355 B2	11/25/03	Wiswesser et al.			06/04/01	
	6,660,633 B1	12/09/03	Lopatin et al.			02/26/02	
	6,678,570 B1	01/13/04	Pasady et al.			06/26/01	
	6,708,074 B1	03/16/04	Chi et al.			08/11/00	
	6,708,075 B2	03/16/04	Sonderman et al.			11/16/01	
	6,725,402 B1	04/20/04	Coss, Jr. et al.			07/31/00	
	6,728,587 B2	04/27/04	Goldman et al.			12/27/00	
	6,735,492 B2	05/11/04	Conrad et al.			07/19/02	
	6,751,518 B1	06/15/04	Sonderman et al.			04/29/02	
	6,774,998 B1	08/10/04	Wright et al.			12/27/01	
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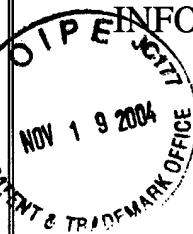
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<b>FOREIGN PATENT DOCUMENTS</b>							
EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						Yes	No
	EP 0 932 195 A1	07/28/99	EP			X	
	EP 1 083 470 A2	03/14/01	EP			X	
	GB 2 365 215 A	02/13/02	GB			X	
<b>OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)</b>							
	IslamRaja, M. M., C. Chang, J. P. McVittie, M. A. Cappelli, and K. C. Saraswat. May/June 1993. "Two Precursor Model for Low-Pressure Chemical Vapor Deposition of Silicon Dioxide from Tetraethylorthosilicate." <i>J. Vac. Sci. Technol. B</i> , Vol. 11, No. 3, pp. 720-726.						
	Kim, Eui Jung and William N. Gill. July 1994. "Analytical Model for Chemical Vapor Deposition of SiO <sub>2</sub> Films Using Tetraethoxysilane and Ozone" (Abstract). <i>Journal of Crystal Growth</i> , Vol. 140, Issues 3-4, pp. 315-326.						
	Sun, S.C. 1998. "CVD and PVD Transition Metal Nitrides as Diffusion Barriers for Cu Metallization." <i>IEEE</i> . pp. 243-246.						
	Guo, R.S., A. Chen, C.L. Tseng, I.K. Fong, A. Yang, C.L. Lee, C.H. Wu, S. Lin, S.J. Huang, Y.C. Lee, S.G. Chang, and M.Y. Lee. June 16-17, 1998. "A Real-Time Equipment Monitoring and Fault Detection System." <i>Semiconductor Manufacturing Technology Workshop</i> , pp. 111-121.						
	Lantz, Mikkil. 1999. "Equipment and APC Integration at AMD with Workstream." <i>IEEE</i> , pp. 325-327.						
	Tagami, M., A. Furuya, T. Onodera, and Y. Hayashi. 1999. "Layered Ta-nitrides (LTN) Barrier Film by Power Swing Sputtering (PSS) Technique for MOCVD-Cu Damascene Interconnects." <i>IEEE</i> . pp. 635-638.						
	Yamagishi, H., Z. Tokei, G.P. Beyer, R. Donaton, H. Bender, T. Nogami, and K. Maex. 2000. "TEM/SEM Investigation and Electrical Evaluation of a Bottomless I-PVD TA(N) Barrier in Dual Damascene" (Abstract). <i>Advanced Metallization Conference 2000</i> . San Diego, CA.						
	Eisenbraun, Eric, Oscar van der Straten, Yu Zhu, Katharine Dovidenko, and Alain Kaloyeros. 2001. "Atomic Layer Deposition (ALD) of Tantalum-Based Materials for Zero Thickness Copper Barrier Applications" (Abstract). <i>IEEE</i> . pp. 207-209.						
	Smith, S.R., K.E. Elers, T. Jacobs, V. Blaschke, and K. Pfeifer. 2001. "Physical and Electrical Characterization of ALD Tin Used as a Copper Diffusion Barrier in 0.25 mum, Dual Damascene Backend Structures" (Abstract). <i>Advanced Metallization Conference 2001</i> . Montreal, Quebec.						
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<b>OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)</b>		
	Kim, Y.T. and H. Sim. 2002. "Characteristics of Pulse Plasma Enhanced Atomic Layer Deposition of Tungsten Nitride Diffusion Barrier for Copper Interconnect" (Abstract). <i>IEIC Technical Report</i> . Vol. 102, No. 178, pp. 115-118.	
	Elers, Kai-Erik, Ville Saanila, Pekka J. Soininen, Wei-Min Li, Juhana T. Kostamo, Suvi Haukka, Jyrki Juhanoja, and Wim F.A. Besling. 2002. "Diffusion Barrier Deposition on a Copper Surface by Atomic Layer Deposition" (Abstract). <i>Advanced Materials</i> . Vol. 14, No. 13-14, pp. 149-153.	
	Peng, C.H., C.H. Hsieh, C.L. Huang, J.C. Lin, M.H. Tsai, M.W. Lin, C.L. Chang, Winston S. Shue, and M.S. Liang. 2002. "A 90nm Generation Copper Dual Damascene Technology with ALD TaN Barrier." <i>IEEE</i> . pp. 603-606.	
	Van der Straten, O., Y. Zhu, E. Eisenbraun, and A. Kaloyeros. 2002. "Thermal and Electrical Barrier Performance Testing of Ultrathin Atomic Layer Deposition Tantalum-Based Materials for Nanoscale Copper Metallization." <i>IEEE</i> . pp. 188-190.	
	Wu, Z.C., Y.C. Lu, C.C. Chiang, M.C. Chen, B.T. Chen, G.J. Wang, Y.T. Chen, J.L. Huang, S.M. Jang, and M.S. Liang. 2002. "Advanced Metal Barrier Free Cu Damascene Interconnects with PECVD Silicon Carbide Barriers for 90/65-nm BEOL Technology." <i>IEEE</i> . pp. 595-598.	
	July 25, 2003. International Search Report for PCT/US02/24858.	
	March 30, 2004. Written Opinion for PCT/US02/19062.	
	April 9, 2004. Written Opinion for PCT/US02/19116.	
	April 22, 2004. Office Action for U.S. Serial No. 09/998,372, filed November 30, 2001.	
	April 28, 2004. Written Opinion for PCT/US02/19117.	
	April 29, 2004. Written Opinion for PCT/US02/19061.	
	May 5, 2004. Office Action for U.S. Serial No. 09/943,955, filed August 31, 2001.	
	May 5, 2004. International Preliminary Examination Report for PCT/US01/27406.	
	May 28, 2004. Office Action for U.S. Serial No. 09/943,383, filed August 31, 2001.	
	June 3, 2004. Office Action for U.S. Serial No. 09/928,474, filed August 14, 2001.	
	June 23, 2004. Office Action for U.S. Serial No. 10/686,589, filed October 17, 2003.	
	June 30, 2004. Office Action for U.S. Serial No. 09/800,980, filed March 8, 2001.	
	July 12, 2004. Office Action for U.S. Serial No. 10/173,108, filed June 8, 2002.	
	July 15, 2004. Office Action for U.S. Serial No. 10/172,977, filed June 18, 2002.	
	August 2, 2004. Office Action for U.S. Serial No. 10/174,377, filed June 18, 2002.	
	August 9, 2004. Written Opinion for PCT Serial No. PCT/US02/19063.	
	August 18, 2004. International Preliminary Examination Report for PCT Serial No. PCT/US02/19116.	
	August 24, 2004. Office Action for U.S. Serial No. 10/135,405, filed May 1, 2002.	
	August 25, 2004. Office Action for U.S. Serial No. 09/998,384, filed November 30, 2001.	
	September 9, 2004. Written Opinion for PCT Serial No. PCT/US02/21942.	
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	September 15, 2004. Office Action for U.S. Serial No. 10/632,107, filed August 1, 2003.	
	September 29, 2004. Office Action for U.S. Serial No. 09/363,966, filed July 29, 1999.	
	October 1, 2004. International Preliminary Examination Report for PCT Serial No. PCT/US03/23964.	
	October 6, 2004. Office Action for U.S. Serial No. 10/759,108, filed January 20, 2004.	
	October 12, 2004. International Preliminary Examination Report for PCT Serial No. PCT/US02/19061.	
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